

● Electrical and optical characteristics (Ta = 25°C)

| Parameter | | Symbol | Min. | Typ. | Max. | Unit | Conditions |
|--------------------------|--------------------------------------|-----------------|------|------|------|---------------|---|
| Input characteristics | Forward voltage | V_F | — | 1.3 | 1.6 | V | $I_F=50\text{mA}$ |
| | Reverse current | I_R | — | — | 10 | μA | $V_R=5\text{V}$ |
| Output characteristics | Dark current | I_{CEO} | — | — | 0.5 | μA | $V_{CE}=10\text{V}$ |
| | Peak sensitivity wavelength | λ_P | — | 800 | — | nm | — |
| Transfer characteristics | Collector current | I_C | 200 | 500 | 1800 | μA | $V_{CC}=5\text{V}$, $I_F=20\text{mA}$, $R_L=100\Omega$, $d=3.5\text{mm}$ |
| | Collector-emitter saturation voltage | $V_{CE(sat)}$ | — | 0.1 | 0.3 | V | $I_F=20\text{mA}$, $I_C=100\mu\text{A}$ |
| | Response time | $t_r \cdot t_f$ | — | 10 | — | μs | $V_{CC}=10\text{V}$, $I_F=20\text{mA}$, $R_L=100\Omega$ |

* Standard paper (90% reflection)

● Electrical and optical characteristic curves

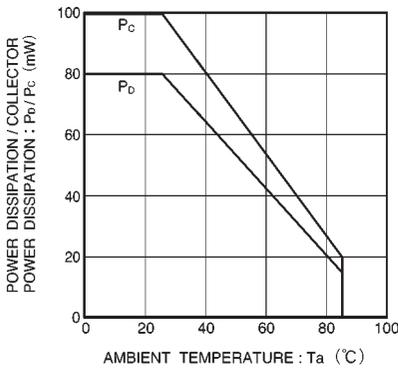


Fig.1 Power dissipation / collector power dissipation vs. ambient temperature

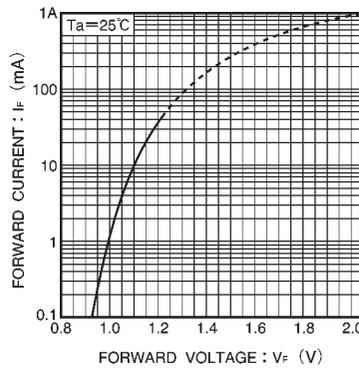


Fig.2 Forward current vs. forward voltage

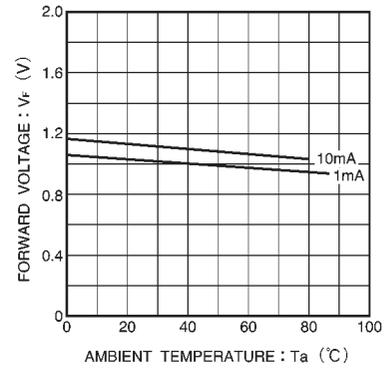


Fig.3 Forward voltage vs. ambient temperature

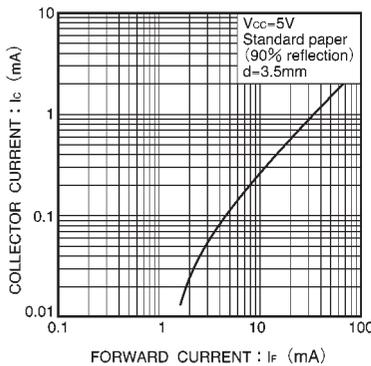


Fig.4 Collector current vs. forward current

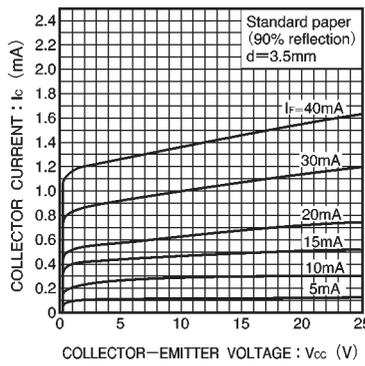


Fig.5 Output characteristics

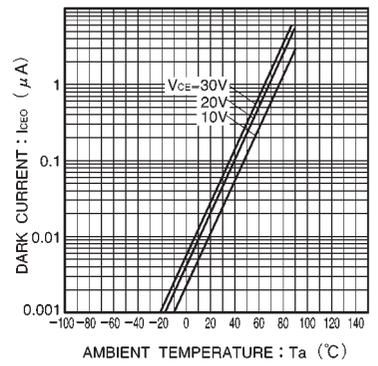


Fig.6 Dark current vs. ambient temperature

Reflective photosensor Cphotorreflector

Photo transistor output

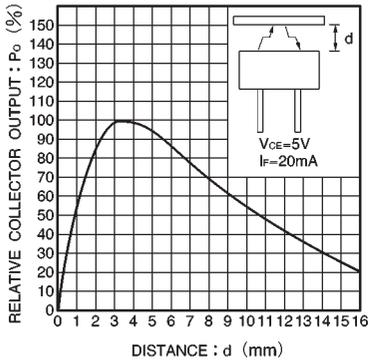


Fig.7 Relative output vs. distance

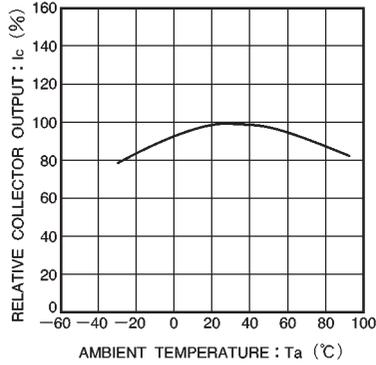


Fig.8 Relative output vs. ambient temperature

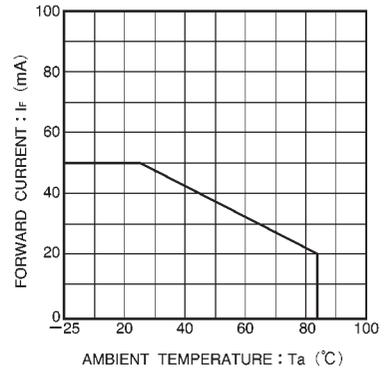


Fig.9 Forward current vs. ambient temperature

● Circuit for testing transfer characteristics

